# 74AHC1G14; 74AHCT1G14

## **Inverting Schmitt trigger**

Rev. 9 — 3 April 2020

**Product data sheet** 

### 1. General description

74AHC1G14 and 74AHCT1G14 are high-speed Si-gate CMOS devices. They provide an inverting buffer function with Schmitt trigger action. These devices are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals.

The AHC device has CMOS input switching levels and supply voltage range 2 V to 5.5 V.

The AHCT device has TTL input switching levels and supply voltage range 4.5 V to 5.5 V.

#### 2. Features and benefits

- · Symmetrical output impedance
- High noise immunity
- ESD protection:
  - HBM JESD22-A114E: exceeds 2000 V
  - MM JESD22-A115-A: exceeds 200 V
  - CDM JESD22-C101C: exceeds 1000 V
- Low power dissipation
- Specified from -40 °C to +125 °C

### 3. Applications

- · Wave and pulse shapers
- Astable multivibrators
- Monostable multivibrators

## 4. Ordering information

**Table 1. Ordering information** 

| Type number  | Package           |        |  |          |  |  |  |  |  |  |
|--------------|-------------------|--------|--|----------|--|--|--|--|--|--|
|              | Temperature range | Name   | Description                                | Version  |  |  |  |  |  |  |
| 74AHC1G14GW  | -40 °C to +125 °C | TSSOP5 | plastic thin shrink small outline package; | SOT353-1 |  |  |  |  |  |  |
| 74AHCT1G14GW |                   |        | 5 leads; body width 1.25 mm                |          |  |  |  |  |  |  |
| 74AHC1G14GV  | -40 °C to +125 °C | SC-74A | plastic surface-mounted package; 5 leads   | SOT753   |  |  |  |  |  |  |
| 74AHCT1G14GV |                   |        |  |          |  |  |  |  |  |  |



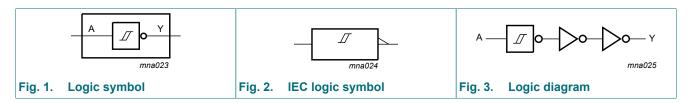
### 5. Marking

#### Table 2. Marking codes

| Type number  | Marking code[1] |
|--------------|-----------------|
| 74AHC1G14GW  | AF              |
| 74AHCT1G14GW | CF              |
| 74AHC1G14GV  | A14             |
| 74AHCT1G14GV | C14             |

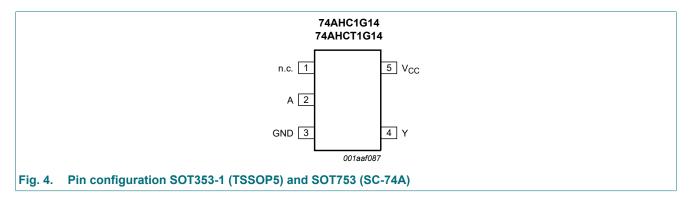
<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

## 6. Functional diagram



### 7. Pinning information

### 7.1. Pinning



### 7.2. Pin description

Table 3. Pin description

| Symbol | Pin | Description    |
|--------|-----|----------------|
| n.c.   | 1   | not connected  |
| A      | 2   | data input     |
| GND    | 3   | ground (0 V)   |
| Υ      | 4   | data output    |
| Vcc    | 5   | supply voltage |

### 8. Functional description

#### **Table 4. Function table**

H = HIGH voltage level; L = LOW voltage level

| Input | Output |
|-------|--------|
| A     | Υ      |
| L     | Н      |
| Н     | L      |

### 9. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter               | Conditions  | Min  | Max  | Unit |
|------------------|-------------------------|---|------|------|------|
| V <sub>CC</sub>  | supply voltage          |   | -0.5 | +7.0 | V    |
| VI               | input voltage           |   | -0.5 | +7.0 | V    |
| I <sub>IK</sub>  | input clamping current  | V <sub>I</sub> < -0.5 V   | -20  | -    | mA   |
| I <sub>OK</sub>  | output clamping current | $V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$ [1]                   | -    | ±20  | mA   |
| I <sub>O</sub>   | output current          | $-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$ | -    | ±25  | mA   |
| I <sub>CC</sub>  | supply current          |   | -    | 75   | mA   |
| I <sub>GND</sub> | ground current          |   | -75  | -    | mA   |
| T <sub>stg</sub> | storage temperature     |   | -65  | +150 | °C   |
| P <sub>tot</sub> | total power dissipation | $T_{amb} = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}$ [2]                | -    | 250  | mW   |

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

### 10. Recommended operating conditions

#### Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter           | Conditions | 74  | AHC1G | 14              | 74  | Unit |                 |    |
|------------------|---------------------|------------|-----|-------|-----------------|-----|------|-----------------|----|
|                  |                     |            | Min | Тур   | Max             | Min | Тур  | Max             |    |
| $V_{CC}$         | supply voltage      |            | 2.0 | 5.0   | 5.5             | 4.5 | 5.0  | 5.5             | V  |
| VI               | input voltage       |            | 0   | -     | 5.5             | 0   | -    | 5.5             | V  |
| Vo               | output voltage      |            | 0   | -     | V <sub>CC</sub> | 0   | -    | V <sub>CC</sub> | V  |
| T <sub>amb</sub> | ambient temperature |            | -40 | +25   | +125            | -40 | +25  | +125            | °C |

**Product data sheet** 

<sup>[2]</sup> For SOT353-1 (TSSOP5) package: P<sub>tot</sub> derates linearly with 3.3 mW/K above 74 °C. For SOT753 (SC-74A) package: P<sub>tot</sub> derates linearly with 3.8 mW/K above 85 °C.

### 11. Static characteristics

#### **Table 7. Static characteristics**

Voltages are referenced to GND (ground = 0 V).

| Symbol                    | Parameter                 | Conditions   |      | 25 °C |      | -40 °C | to +85 °C | -40 °C t | o +125 °C | Unit |
|---------------------------|---------------------------|--|------|-------|------|--------|-----------|----------|-----------|------|
|                           |                           |  | Min  | Тур   | Max  | Min    | Max       | Min      | Max       | 1    |
| For type                  | 74AHC1G14                 |  |      |       |      |        |           |          |           |      |
| V <sub>OH</sub>           | HIGH-level                | $V_I = V_{T+}$ or $V_{T-}$   |      |       |      |        |           |          |           |      |
|                           | output voltage            | I <sub>O</sub> = -50 μA; V <sub>CC</sub> = 2.0 V   | 1.9  | 2.0   | -    | 1.9    | -         | 1.9      | -         | V    |
|                           |                           | I <sub>O</sub> = -50 μA; V <sub>CC</sub> = 3.0 V   | 2.9  | 3.0   | -    | 2.9    | -         | 2.9      | -         | V    |
|                           |                           | I <sub>O</sub> = -50 μA; V <sub>CC</sub> = 4.5 V   | 4.4  | 4.5   | -    | 4.4    | -         | 4.4      | -         | V    |
|                           |                           | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V  | 2.58 | -     | -    | 2.48   | -         | 2.40     | -         | V    |
|                           |                           | I <sub>O</sub> = -8.0 mA; V <sub>CC</sub> = 4.5 V  | 3.94 | -     | -    | 3.8    | -         | 3.70     | -         | V    |
| V <sub>OL</sub> LOW-level |                           | $V_I = V_{T+}$ or $V_{T-}$   |      |       |      |        |           |          |           |      |
|                           | output voltage            | I <sub>O</sub> = 50 μA; V <sub>CC</sub> = 2.0 V  | -    | 0     | 0.1  | -      | 0.1       | -        | 0.1       | V    |
|                           |                           | I <sub>O</sub> = 50 μA; V <sub>CC</sub> = 3.0 V  | -    | 0     | 0.1  | -      | 0.1       | -        | 0.1       | V    |
|                           |                           | I <sub>O</sub> = 50 μA; V <sub>CC</sub> = 4.5 V  | -    | 0     | 0.1  | -      | 0.1       | -        | 0.1       | V    |
|                           |                           | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V   | -    | -     | 0.36 | -      | 0.44      | -        | 0.55      | V    |
|                           |                           | $I_{O}$ = 8.0 mA; $V_{CC}$ = 4.5 V   | -    | -     | 0.36 | -      | 0.44      | -        | 0.55      | V    |
| l <sub>l</sub>            | input leakage<br>current  | V <sub>I</sub> = 5.5 V or GND;<br>V <sub>CC</sub> = 0 V to 5.5 V   | -    | -     | 0.1  | -      | 1.0       | -        | 2.0       | μA   |
| I <sub>CC</sub>           | supply current            | $V_I = V_{CC}$ or GND; $I_O = 0$ A;<br>$V_{CC} = 5.5 \text{ V}$  | -    | -     | 1.0  | -      | 10        | -        | 40        | μA   |
| Cı                        | input<br>capacitance      |  | -    | 1.5   | 10   | -      | 10        | -        | 10        | pF   |
| For type                  | 74AHCT1G14                |  |      |       | I    |        |           | I        |           |      |
| V <sub>OH</sub>           | HIGH-level                | $V_{I} = V_{T+} \text{ or } V_{T-}; V_{CC} = 4.5 \text{ V}$  |      |       |      |        |           |          |           |      |
|                           | output voltage            | I <sub>O</sub> = -50 μA  | 4.4  | 4.5   | -    | 4.4    | -         | 4.4      | -         | V    |
|                           |                           | I <sub>O</sub> = -8.0 mA   | 3.94 | -     | -    | 3.8    | -         | 3.70     | -         | V    |
| V <sub>OL</sub>           | LOW-level                 | $V_{I} = V_{T+} \text{ or } V_{T-}; V_{CC} = 4.5 \text{ V}$  |      |       |      |        |           |          |           |      |
|                           | output voltage            | Ι <sub>Ο</sub> = 50 μΑ   | -    | 0     | 0.1  | -      | 0.1       | -        | 0.1       | V    |
|                           |                           | I <sub>O</sub> = 8.0 mA  | -    | -     | 0.36 | -      | 0.44      | -        | 0.55      | V    |
| l <sub>l</sub>            | input leakage<br>current  | V <sub>I</sub> = 5.5 V or GND;<br>V <sub>CC</sub> = 0 V to 5.5 V   | -    | -     | 0.1  | -      | 1.0       | -        | 2.0       | μΑ   |
| I <sub>CC</sub>           | supply current            | $V_I = V_{CC}$ or GND; $I_O = 0$ A;<br>$V_{CC} = 5.5 \text{ V}$  | -    | -     | 1.0  | -      | 10        | -        | 40        | μΑ   |
| ΔI <sub>CC</sub>          | additional supply current | per input pin; $V_I = 3.4 \text{ V}$ ;<br>other inputs at $V_{CC}$ or GND;<br>$I_O = 0 \text{ A}$ ; $V_{CC} = 5.5 \text{ V}$ | -    | -     | 1.35 | -      | 1.5       | -        | 1.5       | mA   |
| C <sub>I</sub>            | input<br>capacitance      |  | -    | 1.5   | 10   | -      | 10        | -        | 10        | pF   |

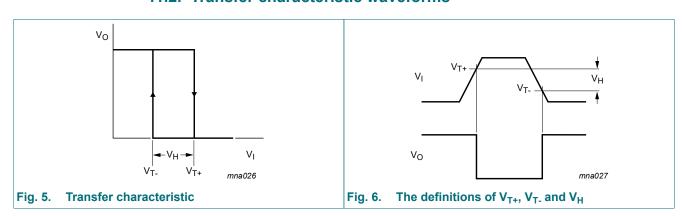
### 11.1. Transfer characteristics

**Table 8. Transfer characteristics** 

At recommended operating conditions; voltages are referenced to GND (ground = 0 V). See Fig. 5 and Fig. 6.

| Symbol              | Parameter             | Conditions              |      | 25 °C |      | -40 °C 1 | to +85 °C | -40 °C t | o +125 °C | Unit |
|---------------------|-----------------------|-------------------------|------|-------|------|----------|-----------|----------|-----------|------|
|                     |                       |                         | Min  | Тур   | Max  | Min      | Max       | Min      | Max       |      |
| For type            | 74AHC1G14             |                         | '    |       |      |          |           |          |           |      |
| $V_{T+}$            | positive-going        | V <sub>CC</sub> = 3.0 V | -    | -     | 2.2  | -        | 2.2       | -        | 2.2       | V    |
|                     | threshold voltage     | V <sub>CC</sub> = 4.5 V | -    | -     | 3.15 | -        | 3.15      | -        | 3.15      | V    |
|                     | Voltage               | V <sub>CC</sub> = 5.5 V | -    | -     | 3.85 | -        | 3.85      | -        | 3.85      | V    |
| V <sub>T-</sub>     | negative-going        | V <sub>CC</sub> = 3.0 V | 0.9  | -     | -    | 0.9      | -         | 0.9      | -         | V    |
| threshol<br>voltage | threshold             | V <sub>CC</sub> = 4.5 V | 1.35 | -     | -    | 1.35     | -         | 1.35     | -         | V    |
|                     | voitage               | V <sub>CC</sub> = 5.5 V | 1.65 | -     | -    | 1.65     | -         | 1.65     | -         | V    |
| $V_{H}$             | hysteresis<br>voltage | V <sub>CC</sub> = 3.0 V | 0.3  | -     | 1.2  | 0.3      | 1.2       | 0.25     | 1.2       | V    |
|                     |                       | V <sub>CC</sub> = 4.5 V | 0.4  | -     | 1.4  | 0.4      | 1.4       | 0.35     | 1.4       | V    |
|                     |                       | V <sub>CC</sub> = 5.5 V | 0.5  | -     | 1.6  | 0.5      | 1.6       | 0.45     | 1.6       | V    |
| For type            | 74AHCT1G14            |                         | ,    |       |      |          |           |          |           |      |
| $V_{T+}$            | positive-going        | V <sub>CC</sub> = 4.5 V | -    | -     | 2.0  | -        | 2.0       | -        | 2.0       | V    |
|                     | threshold voltage     | V <sub>CC</sub> = 5.5 V | -    | -     | 2.0  | -        | 2.0       | -        | 2.0       | V    |
| V <sub>T-</sub>     | negative-going        | V <sub>CC</sub> = 4.5 V | 0.5  | -     | -    | 0.5      | -         | 0.5      | -         | V    |
| threshold voltage   |                       | V <sub>CC</sub> = 5.5 V | 0.6  | -     | -    | 0.6      | -         | 0.6      | -         | V    |
| $V_{H}$             | hysteresis            | V <sub>CC</sub> = 4.5 V | 0.4  | -     | 1.4  | 0.4      | 1.4       | 0.35     | 1.4       | V    |
| l                   | voltage               | V <sub>CC</sub> = 5.5 V | 0.4  | -     | 1.6  | 0.4      | 1.6       | 0.35     | 1.6       | V    |

### 11.2. Transfer characteristic waveforms



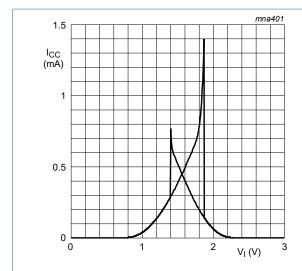


Fig. 7. Typical 74AHC1G14 transfer characteristics;  $V_{CC}$  = 3.0 V

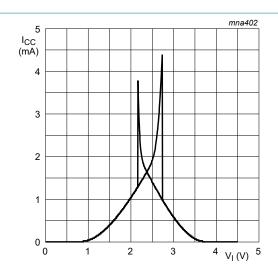


Fig. 8. Typical 74AHC1G14 transfer characteristics;  $V_{CC}$  = 4.5 V

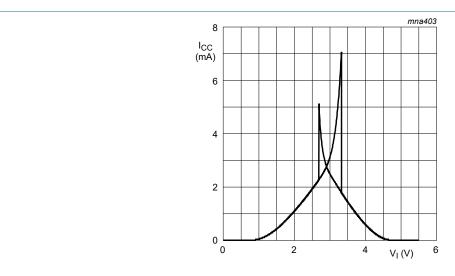


Fig. 9. Typical 74AHC1G14 transfer characteristics;  $V_{CC} = 5.5 \text{ V}$ 

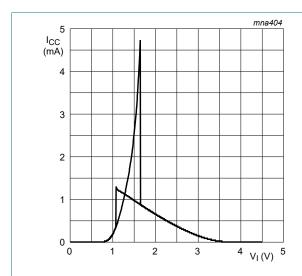


Fig. 10. Typical 74AHCT1G14 transfer characteristics;  $V_{CC}$  = 4.5 V

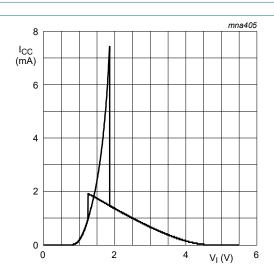


Fig. 11. Typical 74AHCT1G14 transfer characteristics;  $V_{CC}$  = 5.5 V

## 12. Dynamic characteristics

#### **Table 9. Dynamic characteristics**

GND = 0 V;  $t_r = t_f \le 3.0$  ns. For waveform see Fig. 12. For test circuit see Fig. 13.

| Symbol          | Parameter                           | Conditions   |        |     | 25 °C |      | -40 °C | to +85 °C | -40 °C t | o +125 °C | Unit |
|-----------------|-------------------------------------|--|--------|-----|-------|------|--------|-----------|----------|-----------|------|
|                 |                                     |  |        | Min | Тур   | Max  | Min    | Max       | Min      | Max       |      |
| For type        | 74AHC1G14                           |  |        |     |       |      |        |           | 1        |           |      |
| t <sub>pd</sub> | propagation                         | A to Y;  | [1]    |     |       |      |        |           |          |           |      |
|                 | delay                               | V <sub>CC</sub> = 3.0 V to 3.6 V   | [2]    |     |       |      |        |           |          |           |      |
|                 |                                     | C <sub>L</sub> = 15 pF   |        | -   | 4.2   | 12.8 | 1.0    | 15.0      | 1.0      | 16.5      | ns   |
|                 |                                     | C <sub>L</sub> = 50 pF   |        | -   | 6.0   | 16.3 | 1.0    | 18.5      | 1.0      | 20.5      | ns   |
|                 |                                     | V <sub>CC</sub> = 4.5 V to 5.5 V   | [3]    |     |       |      |        |           |          |           |      |
|                 |                                     | C <sub>L</sub> = 15 pF   |        | -   | 3.2   | 8.6  | 1.0    | 10.0      | 1.0      | 11.0      | ns   |
|                 |                                     | C <sub>L</sub> = 50 pF   |        | -   | 4.6   | 10.6 | 1.0    | 12.0      | 1.0      | 13.5      | ns   |
| C <sub>PD</sub> | power<br>dissipation<br>capacitance | per buffer; C <sub>L</sub> = 50 pF;<br>f = 1 MHz;<br>V <sub>I</sub> = GND to V <sub>CC</sub> | [4]    | -   | 12    | -    | -      | -         | -        | -         | pF   |
| For type        | 74AHCT1G1                           | 4  |        |     | ,     |      |        |           |          |           |      |
| t <sub>pd</sub> | propagation delay                   | A to Y;<br>V <sub>CC</sub> = 4.5 V to 5.5 V  | [1][3] |     |       |      |        |           |          |           |      |
|                 |                                     | C <sub>L</sub> = 15 pF   |        | -   | 4.1   | 7.0  | 1.0    | 8.0       | 1.0      | 9.0       | ns   |
|                 |                                     | C <sub>L</sub> = 50 pF   |        | -   | 5.9   | 8.5  | 1.0    | 10.0      | 1.0      | 11.0      | ns   |
| C <sub>PD</sub> | power<br>dissipation<br>capacitance | per buffer;<br>V <sub>I</sub> = GND to V <sub>CC</sub>                                       | [4]    | -   | 13    | -    | -      | -         | -        | -         | pF   |

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in Volts.

 $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ . Typical values are measured at  $V_{CC}$  = 3.3 V. Typical values are measured at  $V_{CC}$  = 5.0 V.

<sup>[4]</sup>  $C_{PD}$  is used to determine the dynamic power dissipation  $P_D$  ( $\mu$ W).

#### 12.1. Waveform and test circuit

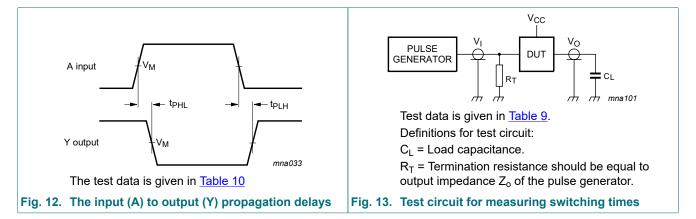


Table 10 Test data

| Table 10. Test data |                        |                       |                       |  |  |  |  |  |
|---------------------|------------------------|-----------------------|-----------------------|--|--|--|--|--|
| Type number         | Input                  | Input                 |                       |  |  |  |  |  |
|                     | V <sub>I</sub>         | V <sub>M</sub>        | V <sub>M</sub>        |  |  |  |  |  |
| 74AHC1G14           | GND to V <sub>CC</sub> | 0.5 x V <sub>CC</sub> | 0.5 x V <sub>CC</sub> |  |  |  |  |  |
| 74AHCT1G14          | GND to 3.0 V           | 1.5 V                 | 0.5 x V <sub>CC</sub> |  |  |  |  |  |

### 13. Application information

The slow input rise and fall times cause additional power dissipation, which can be calculated using the following formula:

 $P_{add} = f_i x (t_r x \Delta I_{CC(AV)} + t_f x \Delta I_{CC(AV)}) x V_{CC}$  where:

- P<sub>add</sub> = additional power dissipation (μW);
- f<sub>i</sub> = input frequency (MHz);
- t<sub>r</sub> = input rise time (ns); 10 % to 90 %;
- t<sub>f</sub> = input fall time (ns); 90 % to 10 %;
- ΔI<sub>CC(AV)</sub> = average additional supply current (μA).

Average additional  $I_{CC}$  differs with positive or negative input transitions, as shown in Fig. 14 and Fig. 15.

For 74AHC1G14 and 74AHCT1G14 used in relaxation oscillator circuit, see Fig. 16.

#### Note to the application information:

· All values given are typical unless otherwise specified.

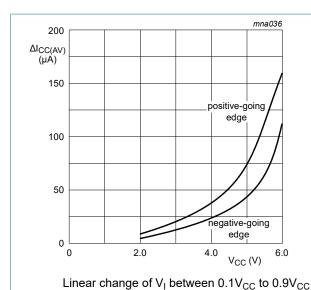
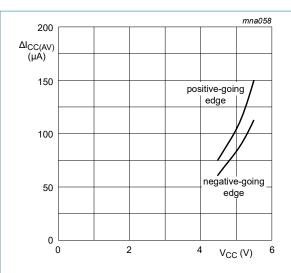
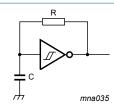


Fig. 14. Average additional I<sub>CC</sub> for 74AHC1G14 Schmitt trigger devices



Linear change of V<sub>I</sub> between 0.1V<sub>CC</sub> to 0.9V<sub>CC</sub>

Fig. 15. Average additional I<sub>CC</sub> for 74AHCT1G14 Schmitt trigger devices



 $f = \frac{1}{T} \approx \frac{1}{K \times RC}$ For K-factor, see Fig. 17

Fig. 16. Relaxation oscillator using the 74AHC1G14 and 74AHCT1G14

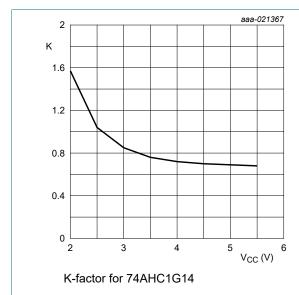
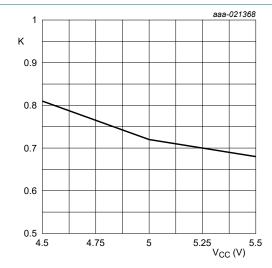


Fig. 17. Typical K-factor for relaxation oscillator

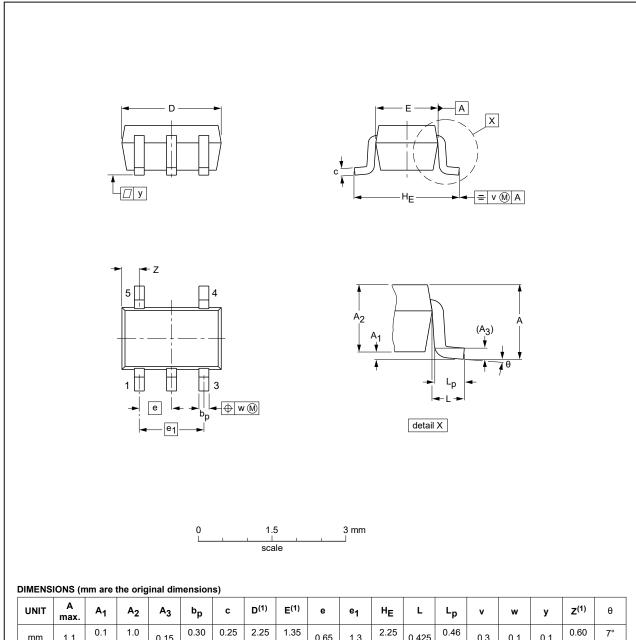


K-factor for 74AHCT1G14

## 14. Package outline

#### TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1



| UNIT | A<br>max. | A <sub>1</sub> | A <sub>2</sub> | А3   | bp           | C            | D <sup>(1)</sup> | E <sup>(1)</sup> | е    | e <sub>1</sub> | HE          | L     | Lp           | v   | w   | у   | Z <sup>(1)</sup> | θ        |
|------|-----------|----------------|----------------|------|--------------|--------------|------------------|------------------|------|----------------|-------------|-------|--------------|-----|-----|-----|------------------|----------|
| mm   | 1.1       | 0.1<br>0       | 1.0<br>0.8     | 0.15 | 0.30<br>0.15 | 0.25<br>0.08 | 2.25<br>1.85     | 1.35<br>1.15     | 0.65 | 1.3            | 2.25<br>2.0 | 0.425 | 0.46<br>0.21 | 0.3 | 0.1 | 0.1 | 0.60<br>0.15     | 7°<br>0° |

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

| OUTLINE  |     | EUROPEAN | ISSUE DATE |  |            |                                  |
|----------|-----|----------|------------|--|------------|----------------------------------|
| VERSION  | IEC | JEDEC    | JEITA      |  | PROJECTION | ISSUE DATE                       |
| SOT353-1 |     | MO-203   | SC-88A     |  |            | <del>-00-09-01</del><br>03-02-19 |

Fig. 18. Package outline SOT353-1 (TSSOP5)

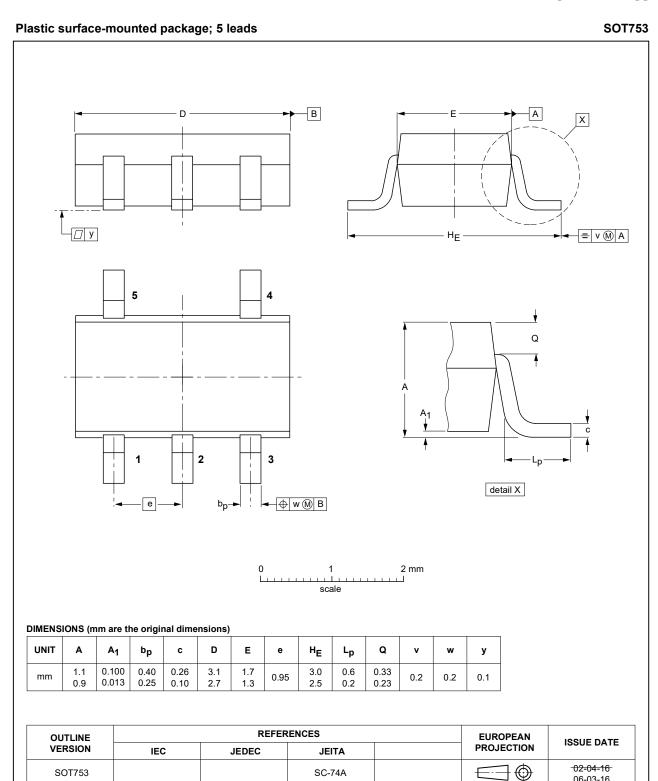


Fig. 19. Package outline SOT753 (SC-74A)

06-03-16

### 15. Abbreviations

#### **Table 11. Abbreviations**

| 14010 1117 (0010 14410110 |   |  |  |  |
|---------------------------|---|--|--|--|
| Acronym                   | Description                             |  |  |  |
| CDM                       | Charged Device Model                    |  |  |  |
| CMOS                      | Complementary Metal-Oxide Semiconductor |  |  |  |
| DUT                       | Device Under Test                       |  |  |  |
| ESD                       | ElectroStatic Discharge                 |  |  |  |
| HBM                       | Human Body Model                        |  |  |  |
| MM                        | Machine Model                           |  |  |  |
| TTL                       | Transistor-Transistor Logic             |  |  |  |

## 16. Revision history

#### **Table 12. Revision history**

| Document ID        | Release date   | Data sheet status     | Change notice | Supersedes         |  |
|--------------------|--|-----------------------|---------------|--------------------|--|
| 74AHC_AHCT1G14 v.9 | 20200403   | Product data sheet    | -             | 74AHC_AHCT1G14 v.8 |  |
| Modifications:     | <ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Table 5: Derating values for P<sub>tot</sub> total power dissipation updated.</li> </ul> |                       |               |                    |  |
| 74AHC_AHCT1G14 v.8 | 20160113   | Product data sheet    | -             | 74AHC_AHCT1G14 v.7 |  |
| Modifications:     | Fig. 17 added (typical K-factor for relaxation oscillator).  |                       |               |                    |  |
| 74AHC_AHCT1G14 v.7 | 20141118   | Product data sheet    | -             | 74AHC_AHCT1G14 v.6 |  |
| Modifications:     | <u>Table 2</u> : table note added.   |                       |               |                    |  |
| 74AHC_AHCT1G14 v.6 | 20090518   | Product data sheet    | -             | 74AHC_AHCT1G14 v.5 |  |
| Modifications:     | <ul> <li><u>Table 7</u>: the conditions for HIGH-level output voltage and LOW-level output voltage have<br/>been changed.</li> </ul>   |                       |               |                    |  |
| 74AHC_AHCT1G14 v.5 | 20070629   | Product data sheet    | -             | 74AHC_AHCT1G14 v.4 |  |
| 74AHC_AHCT1G14 v.4 | 20020528   | Product specification | -             | 74AHC_AHCT1G14 v.3 |  |
| 74AHC_AHCT1G14 v.3 | 20020218   | Product specification | -             | 74AHC_AHCT1G14 v.2 |  |
| 74AHC_AHCT1G14 v.2 | 20010222   | Product specification | -             | 74AHC_AHCT1G14 v.1 |  |
| 74AHC_AHCT1G14 v.1 | 19990805   | Product specification | -             | -                  |  |

### 17. Legal information

#### **Data sheet status**

| Document status [1][2]         | Product<br>status [3] | Definition  |
|--------------------------------|-----------------------|---|
| Objective [short] data sheet   | Development           | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification         | This document contains data from the preliminary specification.                       |
| Product [short]<br>data sheet  | Production            | This document contains the product specification.                                     |

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <a href="https://www.nexperia.com">https://www.nexperia.com</a>.

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### **Contents**

| 1.  | General description                  | 1   |
|-----|--------------------------------------|-----|
| 2.  | Features and benefits                | . 1 |
| 3.  | Applications                         | . 1 |
| 4.  | Ordering information                 |     |
| 5.  | Marking                              | 2   |
| 6.  | Functional diagram                   | 2   |
| 7.  | Pinning information                  | 2   |
| 7.1 | . Pinning                            | 2   |
|     | Pin description                      |     |
| 8.  | Functional description               | 3   |
|     | Limiting values                      |     |
| 10. | Recommended operating conditions     | 3   |
| 11. | Static characteristics               | 4   |
| 11. | 1. Transfer characteristics          | 5   |
| 11. | 2. Transfer characteristic waveforms | . 5 |
| 12. | Dynamic characteristics              | . 7 |
| 12. | Waveform and test circuit            | 8   |
| 13. | Application information              | . 8 |
| 14. | Package outline                      | 10  |
| 15. | Abbreviations                        | 12  |
| 16. | Revision history                     | 12  |
| 17. | Legal information                    | 13  |
|     |                                      |     |

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